

2SC3506

Silicon NPN triple diffusion planar type

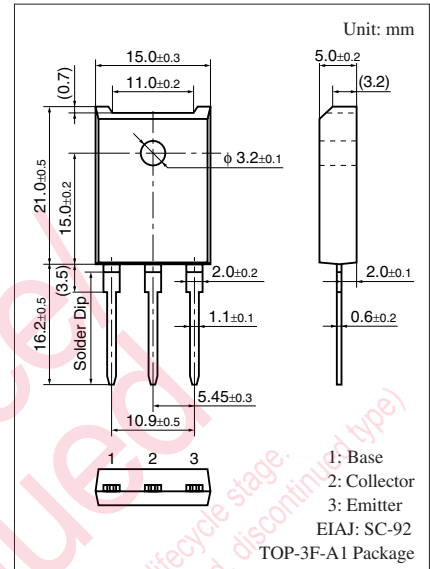
For high-speed switching

■ Features

- High-speed switching
- High collector-base voltage (Emitter open) V_{CBO}
- Satisfactory linearity of forward current transfer ratio h_{FE}
- Full-pack package which can be installed to the heat sink with one screw

■ Absolute Maximum Ratings $T_C = 25^\circ C$

Parameter	Symbol	Rating	Unit
Collector-base voltage (Emitter open)	V_{CBO}	1 000	V
Collector-emitter voltage (E-B short)	V_{CES}	1 000	V
Collector-emitter voltage (Base open)	V_{CEO}	800	V
Emitter-base voltage (Collector open)	V_{EBO}	7	V
Collector current	I_C	3	A
Base current	I_B	2	A
Peak collector current	I_{CP}	6	A
Collector power dissipation	P_C	70	W
	$T_a = 25^\circ C$	3.0	
Junction temperature	T_j	150	$^\circ C$
Storage temperature	T_{stg}	-55 to +150	$^\circ C$

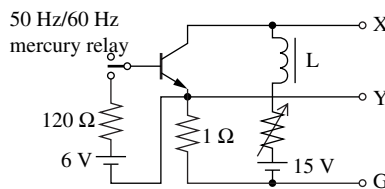


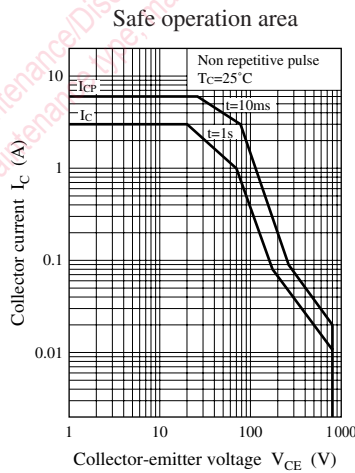
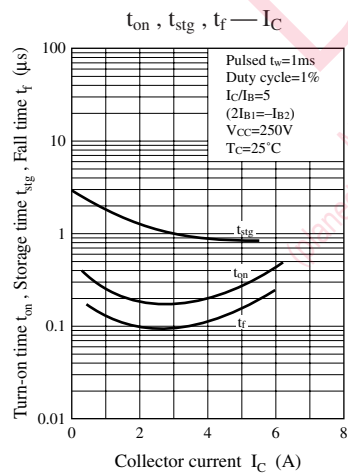
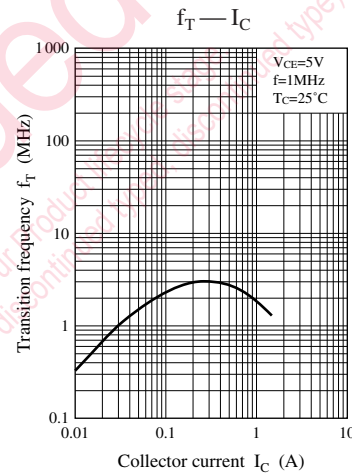
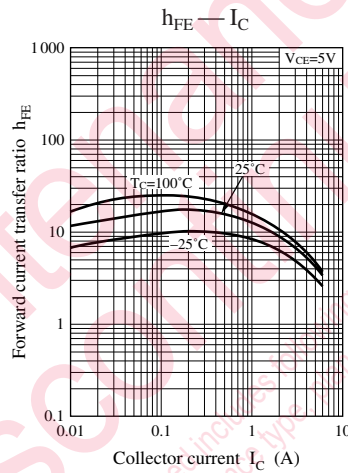
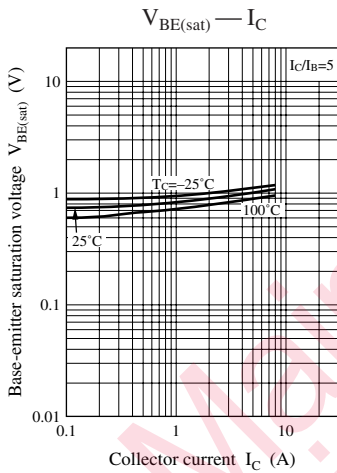
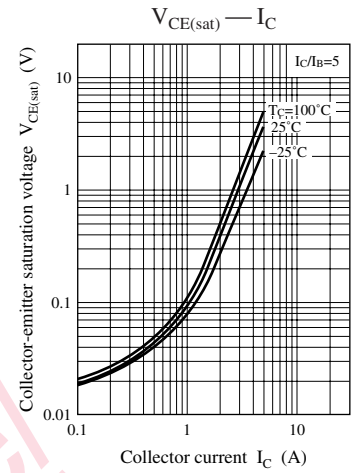
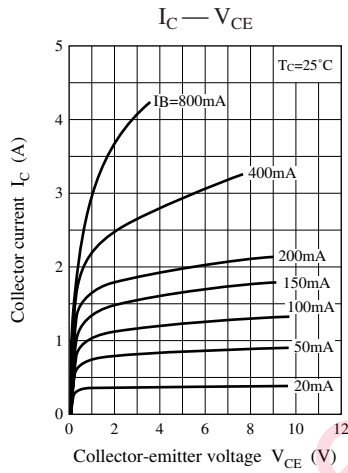
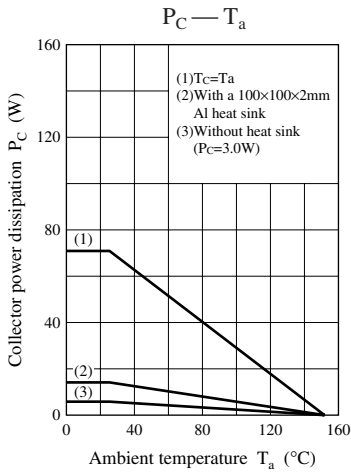
■ Electrical Characteristics $T_C = 25^\circ C \pm 3^\circ C$

Parameter	Symbol	Conditions	Min	Typ	Max	Unit
Collector-emitter sustaining voltage *	$V_{CEO(SUS)}$	$I_C = 0.5 A, L = 50 mH$	800			V
Collector-base cutoff current (Emitter open)	I_{CBO}	$V_{CB} = 1 000 V, I_E = 0$			50	μA
Emitter-base cutoff current (Collector open)	I_{EBO}	$V_{EB} = 7 V, I_C = 0$			50	μA
Forward current transfer ratio	h_{FE}	$V_{CE} = 5 V, I_C = 2 A$	6			—
Collector-emitter saturation voltage	$V_{CE(sat)}$	$I_C = 2 A, I_B = 0.4 A$			1.5	V
Base-emitter saturation voltage	$V_{BE(sat)}$	$I_C = 2 A, I_B = 0.4 A$			1.5	V
Transition frequency	f_T	$V_{CE} = 5 V, I_C = 0.2 A, f = 1 MHz$		4		MHz
Turn-on time	t_{on}	$I_C = 2 A$			1	μs
Storage time	t_{stg}	$I_{B1} = 0.4 A, I_{B2} = -0.8 A$			2.5	μs
Fall time	t_f	$V_{CC} = 250 V$			0.5	μs

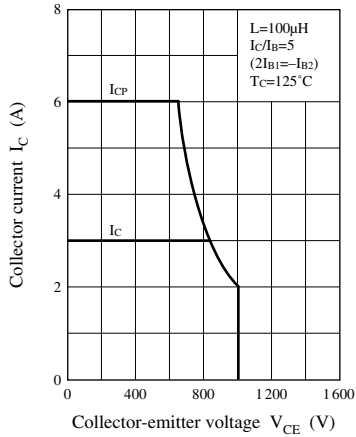
Note) 1. Measuring methods are based on JAPANESE INDUSTRIAL STANDARD JIS C 7030 measuring methods for transistors.

2. *: $V_{CEO(SUS)}$ test circuit

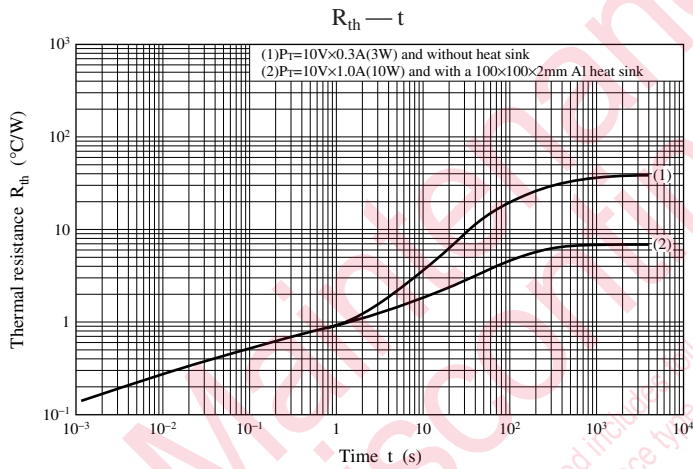
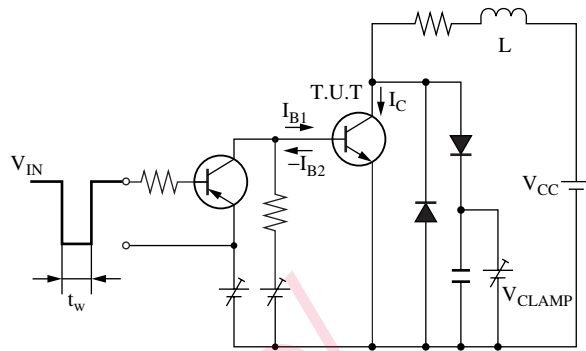




Safe operation area (Reverse bias)



Safe operation area (Reverse bias) measurement circuit



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